

Continental Device India Pvt. Limited An IATF 16949, ISO9001 and ISO 14001 Certified Company



# NPN PLASTIC POWER TRANSISTORS



BD165 BD167 BD169

TO-126 Leaded Plastic Package RoHS compliant

TO-126

Complementary PNP BD166, 168, 170

**APPLICATION:** Audio Amplifier and Driver Circuit Applications

#### **ABSOLUTE MAXIMUM RATINGS** (Ta = 25 °C Unless otherwise specified)

DADAMETED	SYMBOL		VALUE			UNIT	
PARAMETER			BD165	BD167	BD169	UNIT	
Collector-base voltage (open emitter)	V <sub>CBO</sub>	Max	45	60	80	V	
Collector-emitter voltage (open base)	V <sub>CEO</sub>	Max	45	60	80	V	
Collector current	Ι <sub>C</sub>	Max	1.5		1.5 A		
Total power dissipation up to TC = 25°C	P <sub>tot</sub>	Max	20		20 W		
Junction temperature	Тj	Max	150		150 °C		
Collector-emitter saturation voltage $I_{C} = 0.5A; I_{B} = 0.05A$	V <sub>CEsat</sub>	Max	0.5		0.5 V		
D.C. current gain $I_c = 0.15A$ ; $V_{ce} = 2V$	h <sub>FE</sub>	Min	40				
Collector-base voltage (open emitter)	V <sub>CBO</sub>	Max	45	60	80	V	
Collector-emitter voltage (open base)	V <sub>CEO</sub>	Max	45	60	80	V	
Emitter-base voltage (open collector)	V <sub>EBO</sub>	Max		5.0		V	
Collector current	Ι <sub>C</sub>	Max		1.5		А	
Base current	I <sub>B</sub>	Max	0.5		0.5 A		
Total power dissipation up to TA = 25°C	P <sub>tot</sub>	Max	1.25		W		
Derate above 25°C		Max	8		mW/°C		
Total power dissipation up to TC = 25°C	P <sub>tot</sub>	Max	20		W		
Derate above 25°C		Max		160		mW/°C	
Junction temperature	Tj	Max	150		150		°C
Storage temperature	T <sub>stg</sub>	Max	ex -65 to +150		-65 to +150 °C		

#### THERMAL RESISTANCE

From junction to case	R <sub>th j-c</sub>	6.25	°C/W
From junction to ambient	R <sub>th j–a</sub>	100	°C/W

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## ELECTRICAL CHARACTERISTICS at (Ta = 25 °C Unless otherwise specified)

PARAMETER	SYMBOL TEST CONDITION	VALUE				UNIT		
PARAMETER	STMBOL TEST CONDITION			BD165	BD167	BD169		
Collector cutoff current	I <sub>CBO</sub>	I <sub>E</sub> = 0; V <sub>CB</sub> = 45V	Max	0.1			mA	
	I <sub>CBO</sub>	I <sub>E</sub> = 0; V <sub>CB</sub> = 60V	Max		0.1		mA	
	I <sub>CBO</sub>	I <sub>E</sub> = 0; V <sub>CB</sub> = 80V	Max			0.1	mA	
Emitter cut-off current	I <sub>EBO</sub>	I <sub>C</sub> = 0; V <sub>EB</sub> = 5V	Max		1.0		mA	
Breakdown voltages	$V_{CEO(sus)}^{1}$	I <sub>C</sub> = 0.1A; I <sub>B</sub> = 0	Min	45	60	80	V	
	V <sub>CBO</sub>	I <sub>C</sub> = 1mA; I <sub>E</sub> = 0	Min	45	60	80	V	
	V <sub>EBO</sub>	I <sub>E</sub> = 1mA; I <sub>C</sub> = 0	Min		5.0		V	
DC current gain	ь <sup>1</sup>	I <sub>C</sub> = 0.15A; V <sub>CE</sub> = 2V	Min	40				
	h <sub>FE</sub> <sup>1</sup>	I <sub>C</sub> = 0.5A; V <sub>CE</sub> = 2V	Min	15				
Saturation voltage	V <sub>CE(sat)</sub> <sup>1</sup>	I <sub>C</sub> = 0.5A; I <sub>B</sub> = 0.05A	Max		0.5		V	
Base-emitter on voltage	$VB_{E(on)}^{1}$	I <sub>C</sub> = 0.5 A; V <sub>CE</sub> = 2V	Max		0.95		V	
Transition frequency f = 1 MHz	f <sub>T</sub>	I <sub>C</sub> = 500 mA; V <sub>CE</sub> = 2V	Min		6.0		MHz	
Note:				<u>I</u>				

Note:

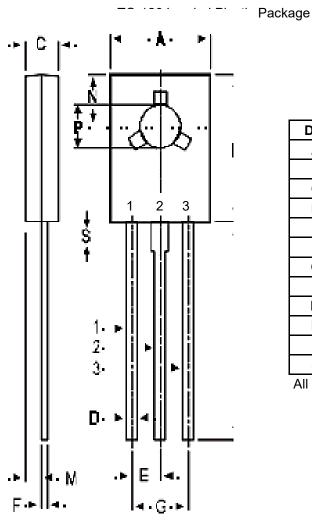
1. Pulse test: pulse width  $\leq$  300 µs; duty cycle  $\leq$  2%



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## PACKAGE DETAILS



DIN	MIN.	MAX.	
А	7.4	7.8	
В	10.5	10.8	
С	2.4	2.7	
D	0.7	0.9	
Е	2.25 TYP.		
F	0.49	0.75	
G	4.5 TYP.		
L	15.7 TYP.		
М	1.27 TYP.		
Ν	3.75 TYP.		
Р	3.0	3.2	
S	2.5 TYP.		
A 11 11			

All dimensions are in mm

## **Pin Configuration**

- 1. EMITTER
- 2. COLLECTOR
- 3. BASE

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### Recommended Product Storage Environment for Discrete Semiconductor Devices

This storage environment assumes that the Diodes and transistors are packed properly inside the original packing supplied by CDIL.

- · Temperature 5 °C to 30 °C
- · Humidity between 40 to 70 %RH
- · Air should be clean.
- · Avoid harmful gas or dust.
- · Avoid outdoor exposure or storage in areas subject to rain or water spraying .
- · Avoid storage in areas subject to corrosive gas or dust. Product shall not be stored in areas exposed to direct sunlight.
- · Avoid rapid change of temperature.
- · Avoid condensation.
- · Mechanical stress such as vibration and impact shall be avoided.
- · The product shall not be placed directly on the floor.
- The product shall be stored on a plane area. They should not be turned upside down. They should not be placed against the wall.

#### Shelf Life of CDIL Products

The shelf life of products is the period from product manufacture to shipment to customers. The product can be unconditionally shipped within this period. The period is defined as 2 years.

If products are stored longer than the shelf life of 2 years the products shall be subjected to quality check as per CDIL quality procedure.

The products are further warranted for another one year after the date of shipment subject to the above conditions in CDIL original packing.

#### Floor Life of CDIL Products and MSL Level

When the products are opened from the original packing, the floor life will start. For this, the following JEDEC table may be referred:

JEDEC MSL Level					
Level	Time	Condition			
1	Unlimited	≤30 °C / 85% RH			
2	1 Year	≤30 °C / 60% RH			
2a	4 Weeks	≤30 °C / 60% RH			
3	168 Hours	≤30 °C / 60% RH			
4	72 Hours	≤30 °C / 60% RH			
5	48 Hours	≤30 °C / 60% RH			
5a	24 Hours	≤30 °C / 60% RH			
6	Time on Label(TOL)	≤30 °C / 60% RH			





#### **Customer Notes**

#### **Component Disposal Instructions**

- 1. CDIL Semiconductor Devices are RoHS compliant, customers are requested to please dispose as per prevailing Environmental Legislation of their Country.
- 2. In Europe, please dispose as per EU Directive 2002/96/EC on Waste Electrical and Electronic Equipment (WEEE).

#### Disclaimer

The product information and the selection guides facilitate selection of the CDIL's Semiconductor Device(s) best suited for application in your product(s) as per your requirement. It is recommended that you completely review our Data Sheet(s) so as to confirm that the Device(s) meet functionality parameters for your application. The information furnished in the Data Sheet and on the CDIL Web Site/CD are believed to be accurate and reliable. CDIL however, does not assume responsibility for inaccuracies or incomplete information. Furthermore, CDIL does not assume liability whatsoever, arising out of the application or use of any CDIL product; neither does it convey any license under its patent rights nor rights of others. These products are not designed for use in life saving/support appliances or systems. CDIL customers selling these products (either as individual Semiconductor Devices or incorporated in their end products), in any life saving/support appliances or systems or applications do so at their own risk and CDIL will not be responsible for any damages resulting from such sale(s).

CDIL strives for continuous improvement and reserves the right to change the specifications of its products without prior notice.



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